

DOCUMENT CHANGE REQUEST

1156 DCR number Originator: Steve Thacker Changes required for: General Date: 2018/10/29 Date sent: 2018/04/09 Organisation: ESCC Executive Secretariat Status: IMPLEMENTED Title: Transistors, Microwave, Small Signal, Silicon, Bipolar, based on Type BFY740B Number: 5611/011 Issue: 3 Other documents affected: Page: See attachment 5611/011 Draft 4B Paragraph: See below and in attachment 5611/011 Draft 4B Original wording: See 5611/011 issue 3 Proposed wording: The following changes are proposed as detailed (highlighted yellow) in the attachment: ESCC5611011 Draft 4B in review.docx: A) Various minor editorial changes are implemented as highlighted in the attachment. B) Para 1.4.2: add new Variant 02 with different die metallisation compared to Variant 01 (Die Metallisation column is also added to table) C) Para 2.1.1: Add new deviation on Radiographic Inspection during Screening Tests. D) Para 2.5.1 Characteristic ICEX: new limits are added for new Variant 02. Justification:

The technical changes included above (points B C D) are as proposed by ESCC Qualified Manufacturer Infineon.

Attachments:
escc5611011_draft_4b_in_review.docx
Modifications:
N/A
Approval signature:
Lucian Rem
Date signed:
2018-10-29